## NSN 5961-00-954-9599

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-954-9599

Inclosure Material:

Metal

**Overall Length:** 

0.535 inches

#### **Overall Diameter:**

0.380 inches

#### Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

#### Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

0.437 inches

#### Thread Size:

0.190 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 10.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 1.00 amperes source cutoff current and 2.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

40.0 watts small-signal input power, common-collector

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

3 tab, solder lug

#### **Specification Data:**

80131-release4663 professional/industrial association specification

#### Shelf Life:

N/a

#### Unit Of Measure:

# NSN 5961-00-954-9599

Transistor - Page 2 of 2

Demilitarization:

No

Fiig:

A110a0

